

vPolyTan™ Polymer Surface-Mount Chip Capacitors, Molded Case, High Performance, Vishay Automotive Grade



LINKS TO ADDITIONAL RESOURCES



PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +125 °C
(above 105 °C, voltage derating is required)
Capacitance Range: 2.2 µF to 680 µF
Capacitance Tolerance: ± 20 %
Voltage Rating: 2.5 V_{DC} to 35 V_{DC}

FEATURES

- Operating temperature range of -55 °C to +125 °C
- 100 % surge current tested
- High temperature and humidity 85 °C / 85 % RH rated voltage capability
- AEC-Q200 qualified
- Ultra low ESR
- Molded case 3528-21, 7343-20, 7343-31 EIA size
- Terminations: 100 % tin
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE


RoHS
COMPLIANT

 HALOGEN
FREE
GREEN
(5-2008)

APPLICATIONS

- Decoupling, smoothing, filtering
- Switch mode and point of load power supply
- Automotive - infotainment and cockpit electronics
- Storage and networking infrastructure equipment
- Industrial applications requiring high temperature operation

ORDERING INFORMATION

T51 TYPE	D CASE CODE	107 CAPACITANCE	M CAPACITANCE TOLERANCE	010 DC VOLTAGE RATING	C TERMINATION / PACKAGING	0040 ESR
	See Ratings and Case Codes table.	This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	M = ± 20 %	2R5 = 2.5 V 004 = 4 V 6R3 = 6.3 V 010 = 10 V 016 = 16 V 020 = 20 V 025 = 25 V 035 = 35 V	C = lead (Pb)-free solderable coating, 7" reel	Maximum 100 kHz ESR in mΩ

Note

- We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size. Voltage substitutions will be marked with the higher voltage rating

DIMENSIONS in inches [millimeters]

D, V, case

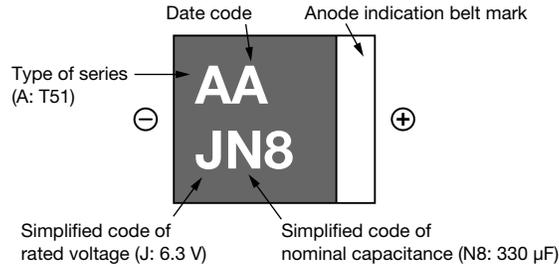
CASE CODE	EIA SIZE	L	W	H	I	a
V	7343-20	0.287 ± 0.008 [7.3 ± 0.2]	0.169 ± 0.012 [4.3 ± 0.3]	0.075 ± 0.004 [1.9 ± 0.1]	0.051 ± 0.012 [1.3 ± 0.3]	0.094 ± 0.008 [2.4 ± 0.2]
D	7343-31	0.287 ± 0.008 [7.3 ± 0.2]	0.169 ± 0.012 [4.3 ± 0.3]	0.110 ± 0.012 [2.8 ± 0.3]	0.051 ± 0.012 [1.3 ± 0.3]	0.094 ± 0.008 [2.4 ± 0.2]

DIMENSIONS in inches [millimeters]						
<p>B case</p> <p>Anode indication belt mark</p>						
CASE CODE	EIA SIZE	L	W	H	I	a
B	3528-21	0.138 ± 0.008 [3.5 ± 0.2]	0.110 ± 0.008 [2.8 ± 0.2]	0.075 ± 0.008 [1.9 ± 0.2]	0.030 ± 0.012 [0.8 ± 0.3]	0.087 ± 0.008 [2.2 ± 0.2]

RATINGS AND CASE CODES (ESR mΩ)								
μF	2.5 V	4.0 V	6.3 V	10 V	16 V	20 V	25 V	35 V
2.2								B ⁽¹⁾ (300)
3.3								B ⁽¹⁾ (300)
4.7							B ⁽¹⁾ (300)	B ⁽¹⁾ (300)
6.8								D (120)
10						B ⁽¹⁾ (300)	D (120)	D (120), D ⁽¹⁾ (70)
15						B ⁽¹⁾ (300)	D (100), D ⁽¹⁾ (70)	
22			B (70)	B ⁽¹⁾ (70)		B ⁽¹⁾ (300) / D ⁽¹⁾ (70)	D (100)	
33		B (70)	B (70)	B ⁽¹⁾ (70)	V ⁽¹⁾ (70) / D (70)	D (100)	D (100, 60)	
47		B (70)	B (70)	B ⁽¹⁾ (70)	V ⁽¹⁾ (70) / D (70)	V ⁽¹⁾ (70) / D (70)	D (60)	
68		B (70)	B (70)	D (40, 25)	D (70)			
100	B (70), B ⁽¹⁾ (55)	B (70), B ⁽¹⁾ (55)	B (70)	D (40, 25)	D (50)			
150	B (70)	B (70) / D (40)	D (40, 25)	D (40, 25)	D (65)			
220	B (45) / V (40) / D (25), D ⁽¹⁾ (9)	V ⁽¹⁾ (25) D (40, 25)	B ⁽¹⁾ (70) / D (40, 25)	D (40, 25)				
330	V (40) / D (25), D ⁽¹⁾ (9)	D (40, 25)	B ⁽¹⁾ (70) / D (40, 25)					
470	D (25, 9, 6)	D (25)						
680	D ⁽¹⁾ (9, 6)	D (25)						

Note

⁽¹⁾ Rating in development, contact factory for availability

MARKING


VOLTAGE CODE		CAPACITANCE CODE	
V	CODE	CAP, μF	CODE
2.5	e	2.2	J6
4	G	3.3	N6
6.3	J	4.7	S6
10	A	6.8	W6
16	C	10	A7
20	D	15	E7
25	E	22	J7
35	V	33	N7
		47	S7
		68	W7
		100	A8
		150	E8
		220	J8
		330	N8
		470	S8
		680	W8

DATE CODE

YEAR	MONTH											
	1	2	3	4	5	6	7	8	9	10	11	12
2021	A	B	C	D	E	F	G	H	J	K	L	M
2022	N	P	Q	R	S	T	U	V	W	X	Y	Z
2023	a	b	c	d	e	f	g	h	j	k	l	m
2024	n	p	q	r	s	t	u	v	w	x	y	z
2025	A	B	C	D	E	F	G	H	J	K	L	M
2026	N	P	Q	R	S	T	U	V	W	X	Y	Z

Note

- Marking code repeats every four years in alphabetical order (letter of l, i, O, and o are excluded)



STANDARD RATINGS							
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μ A)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT 25 °C 100 kHz (m Ω)	MAX. RIPPLE AT 45 °C 100 kHz I _{RMS} (A)	HIGH TEMPERATURE LOAD, TIME (h)
2.5 V_{DC} AT +105 °C							
100	B	T51B107M2R5C0070	25.0	8	70	1.38	2000
100	B ⁽¹⁾	T51B107M2R5C0055	25.0	8	55	1.56	2000
150	B	T51B157M2R5C0070	37.5	8	70	1.38	2000
220	B	T51B227M2R5C0045	55.0	8	45	1.73	2000
220	V	T51V227M2R5C0040	55.0	10	40	3.16	2000
220	D	T51D227M2R5C0025	55.0	10	25	4.24	2000
220	D ⁽¹⁾	T51D227M2R5C0009	55.0	10	9	7.07	2000
330	V	T51V337M2R5C0040	82.5	10	40	3.16	2000
330	D	T51D337M2R5C0025	82.5	10	25	4.24	2000
330	D ⁽¹⁾	T51D337M2R5C0009	82.5	10	9	7.07	2000
470	D	T51D477M2R5C0025	117.5	10	25	4.24	2000
470	D	T51D477M2R5C0009	117.5	10	9	7.07	1000
470	D	T51D477M2R5C0006	117.5	10	6	8.66	1000
680	D ⁽¹⁾	T51D687M2R5C0009	170.0	10	9	7.07	2000
680	D ⁽¹⁾	T51D687M2R5C0006	170.0	10	6	8.66	2000
4 V_{DC} AT +105 °C							
33	B	T51B336M004C0070	13.2	8	70	1.38	2000
47	B	T51B476M004C0070	18.8	8	70	1.38	2000
68	B	T51B686M004C0070	27.2	8	70	1.38	2000
100	B	T51B107M004C0070	40.0	8	70	1.38	2000
100	B ⁽¹⁾	T51B107M004C0055	40.0	8	55	1.56	2000
150	B	T51B157M004C0070	60.0	8	70	1.38	2000
150	D	T51D157M004C0040	60.0	10	40	3.35	2000
220	V ⁽¹⁾	T51V227M004C0025	88.0	10	25	4.00	2000
220	D	T51D227M004C0040	88.0	10	40	3.35	2000
220	D	T51D227M004C0025	88.0	10	25	4.24	2000
330	D	T51D337M004C0040	132.0	10	40	3.35	2000
330	D	T51D337M004C0025	132.0	10	25	4.24	2000
470	D	T51D477M004C0025	188.0	10	25	4.24	2000
6.3 V_{DC} AT +105 °C							
22	B	T51B226M6R3C0070	13.9	8	70	1.38	2000
33	B	T51B336M6R3C0070	20.8	8	70	1.38	2000
47	B	T51B476M6R3C0070	29.6	8	70	1.38	2000
68	B	T51B686M6R3C0070	42.8	8	70	1.38	2000
100	B	T51B107M6R3C0070	63.0	8	70	1.38	2000
150	D	T51D157M6R3C0040	94.5	10	40	3.35	2000
150	D	T51D157M6R3C0025	94.5	10	25	4.24	2000
220	B ⁽¹⁾	T51B227M6R3C0070	138.6	8	70	1.38	2000
220	D	T51D227M6R3C0040	138.6	10	40	3.35	2000
220	D	T51D227M6R3C0025	138.6	10	25	4.24	2000
330	B ⁽¹⁾	T51B337M6R3C0070	207.9	8	70	1.38	2000
330	D	T51D337M6R3C0040	207.9	10	40	3.35	2000
330	D	T51D337M6R3C0025	207.9	10	25	4.24	2000

Note

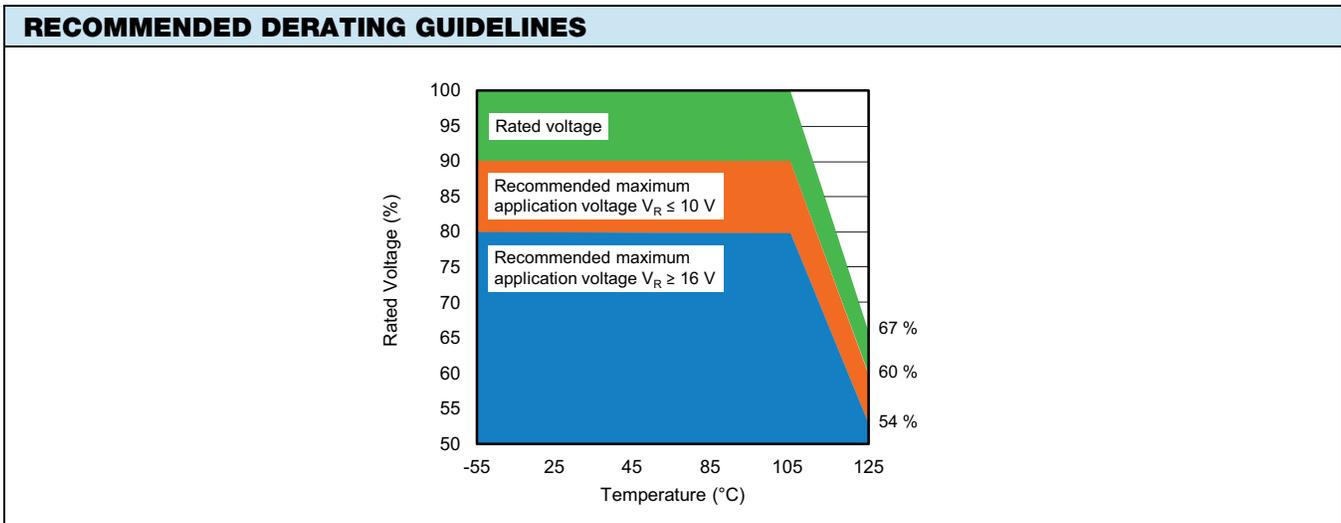
(1) Rating in development, contact factory for availability



STANDARD RATINGS							
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μ A)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT 25 °C 100 kHz (m Ω)	MAX. RIPPLE AT 45 °C 100 kHz I _{RMS} (A)	HIGH TEMPERATURE LOAD, TIME (h)
10 V_{DC} AT +105 °C							
22	B ⁽¹⁾	T51B226M010C0070	22.0	8	70	1.38	2000
33	B ⁽¹⁾	T51B336M010C0070	33.0	8	70	1.38	2000
47	B ⁽¹⁾	T51B476M010C0070	47.0	8	70	1.38	2000
68	D	T51D686M010C0040	68.0	10	40	3.35	2000
68	D	T51D686M010C0025	68.0	10	25	4.24	2000
100	D	T51D107M010C0040	100.0	10	40	3.35	2000
100	D	T51D107M010C0025	100.0	10	25	4.24	2000
150	D	T51D157M010C0040	150.0	10	40	3.35	2000
150	D	T51D157M010C0025	150.0	10	25	4.24	2000
220	D	T51D227M010C0040	220.0	10	40	3.35	2000
220	D	T51D227M010C0025	220.0	10	25	4.24	2000
16 V_{DC} AT +105 °C							
33	V ⁽¹⁾	T51V336M016C0070	52.8	10	70	2.39	2000
33	D	T51D336M016C0070	52.8	10	70	2.53	2000
47	V ⁽¹⁾	T51V476M016C0070	75.2	10	70	2.39	2000
47	D	T51D476M016C0070	75.2	10	70	2.53	2000
68	D	T51D686M016C0070	108.8	10	70	2.53	2000
100	D	T51D107M016C0050	160.0	10	50	3.00	2000
150	D	T51D157M016C0065	240.0	10	65	2.63	2000
20 V_{DC} AT +105 °C							
10	B ⁽¹⁾	T51B106M020C0300	20.0	8	300	0.67	2000
15	B ⁽¹⁾	T51B156M020C0300	30.0	8	300	0.67	2000
22	B ⁽¹⁾	T51B226M020C0300	44.0	8	300	0.67	2000
22	D ⁽¹⁾	T51D226M020C0070	44.0	10	70	2.53	2000
33	D	T51D336M020C0100	66.0	10	100	2.12	2000
47	V ⁽¹⁾	T51V476M020C0070	94.0	10	70	2.39	2000
47	D	T51D476M020C0070	94.0	10	70	2.53	2000
25 V_{DC} AT +105 °C							
4.7	B ⁽¹⁾	T51B475M025C0300	11.8	8	300	0.67	2000
10	D	T51D106M025C0120	25.0	10	120	1.93	2000
15	D	T51D156M025C0100	37.5	10	100	2.12	2000
15	D ⁽¹⁾	T51D156M025C0070	37.5	10	70	2.53	2000
22	D	T51D226M025C0100	55.0	10	100	2.12	2000
33	D	T51D336M025C0100	82.5	10	100	2.12	2000
33	D	T51D336M025C0060	82.5	10	60	2.73	2000
47	D	T51D476M025C0060	117.5	10	60	2.73	2000
35 V_{DC} AT +105 °C							
2.2	B ⁽¹⁾	T51B225M035C0300	7.7	8	300	0.67	2000
3.3	B ⁽¹⁾	T51B335M035C0300	11.6	8	300	0.67	2000
4.7	B ⁽¹⁾	T51B475M035C0300	16.5	8	300	0.67	2000
6.8	D	T51D685M035C0120	23.8	10	120	1.93	2000
10	D	T51D106M035C0120	35.0	10	120	1.93	2000
10	D ⁽¹⁾	T51D106M035C0070	35.0	10	70	2.53	2000

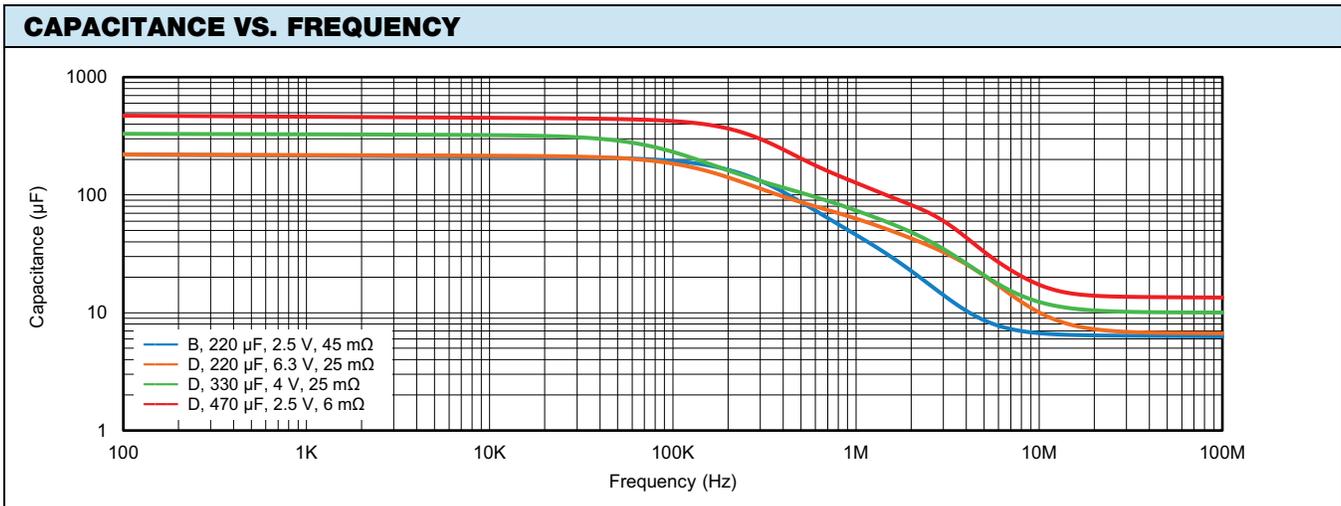
Note

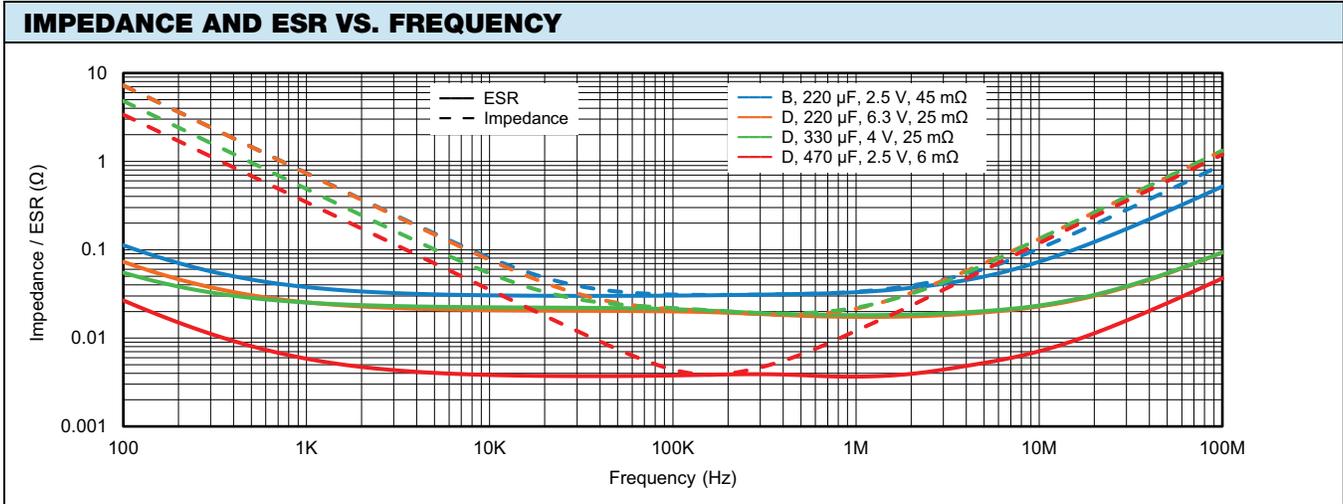
(1) Rating in development, contact factory for availability



RECOMMENDED VOLTAGE DERATING GUIDELINES

CAPACITOR VOLTAGE RATING AT -55 °C TO +105 °C	CAPACITOR CATEGORY VOLTAGE ABOVE +105 °C TO +125 °C	RECOMMENDED VOLTAGE DERATING AT -55 °C TO +105 °C	RECOMMENDED VOLTAGE DERATING ABOVE +105 °C TO +125 °C
2.5	1.7	2.3	1.5
4.0	2.7	3.6	2.4
6.3	4.2	5.7	3.8
10	6.7	9.0	6.0
16	10.7	12.8	8.6
20	13.4	16	10.8
25	16.8	20	13.5
35	23.5	28	18.9





POWER DISSIPATION	
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION (W) AT +45 °C IN FREE AIR
B	0.135
V	0.400
D	0.450

STANDARD PACKAGING QUANTITY	
CASE CODE	UNITS PER 7" REEL
B	2000
V	800
D	500

AEC-Q200 QUALIFICATION TESTING		
NO.	AEC-Q200 TEST ITEM	REFERENCE
1	Pre- and post-stress electrical test	Internal spec.
3	High temperature exposure (storage)	AEC-Q200
4	Temperature cycling	AEC-Q200
7	Biased humidity	AEC-Q200
8	Operational life	AEC-Q200
9	External visual	AEC-Q200
10	Physical dimension	AEC-Q200
12	Resistance to solvents	AEC-Q200
13	Mechanical shock	AEC-Q200
14	Vibration	AEC-Q200
15	Resistance to soldering heat	AEC-Q200
17	ESD	AEC-Q200
18	Solderability	AEC-Q200
19	Electrical characterization	Internal spec.
22	Terminal strength (SMD)	AEC-Q200

PRODUCT INFORMATION	
Polymer Guide	www.vishay.com/doc?40076
Moisture Sensitivity	www.vishay.com/doc?40135
Infographic	www.vishay.com/doc?48084
Sample Board	www.vishay.com/doc?48073
FAQ	
Frequently Asked Questions	www.vishay.com/doc?42106



Guide for Tantalum Solid Electrolyte Chip Capacitors With Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS	
DIELECTRIC	ϵ DIELECTRIC CONSTANT
Air or vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral oil	2.2 to 2.3
Silicone oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum oxide	8.4
Tantalum pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

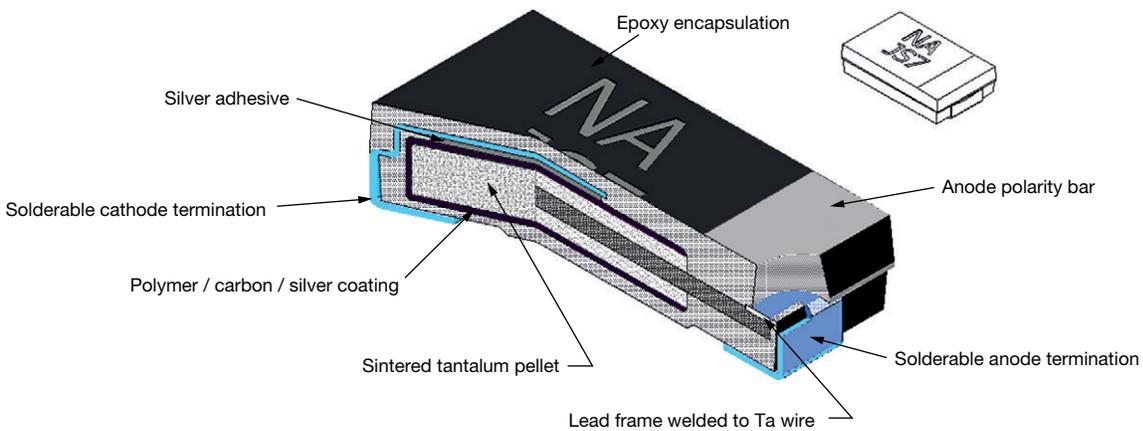
SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

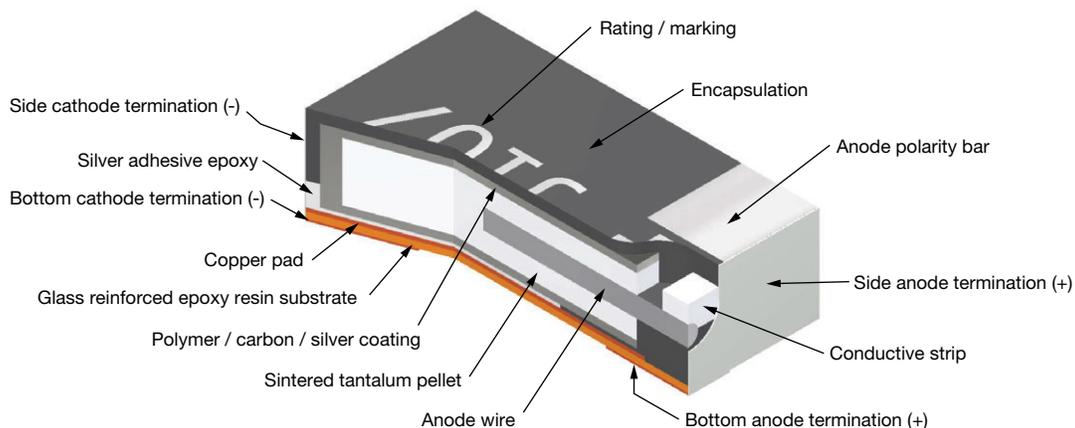
The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. The molding compound has been selected to meet the requirements of UL 94 V-0 and outgassing requirements of ASTM E-595. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.

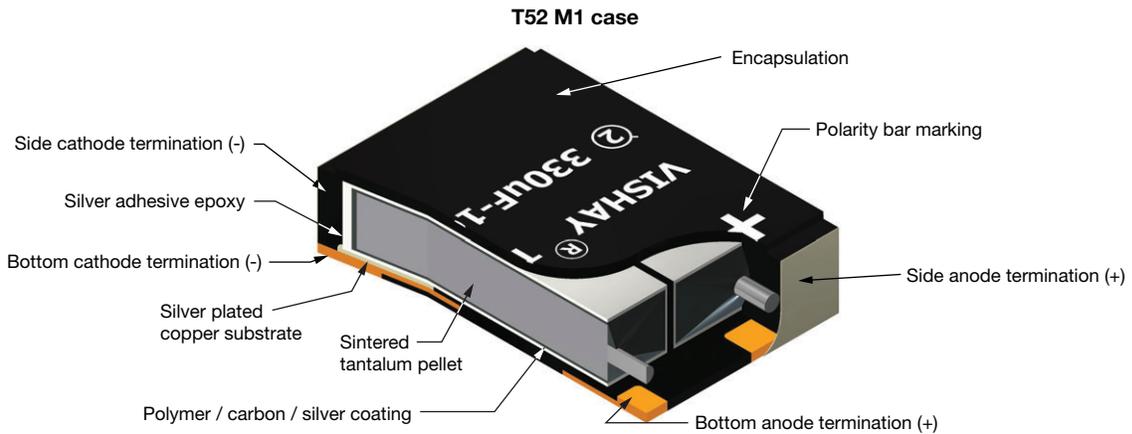
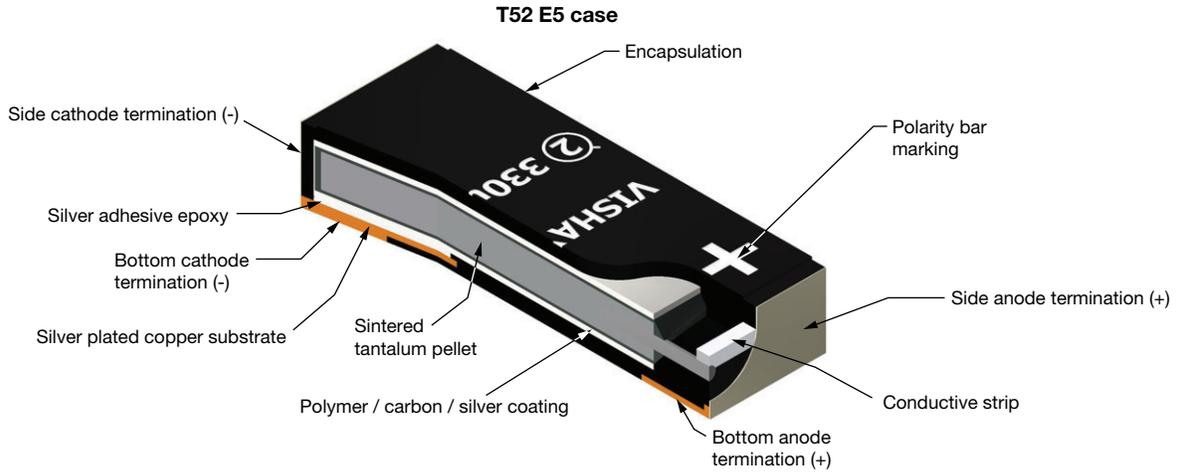
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T50 / T51 / T55 / T56 / 04051



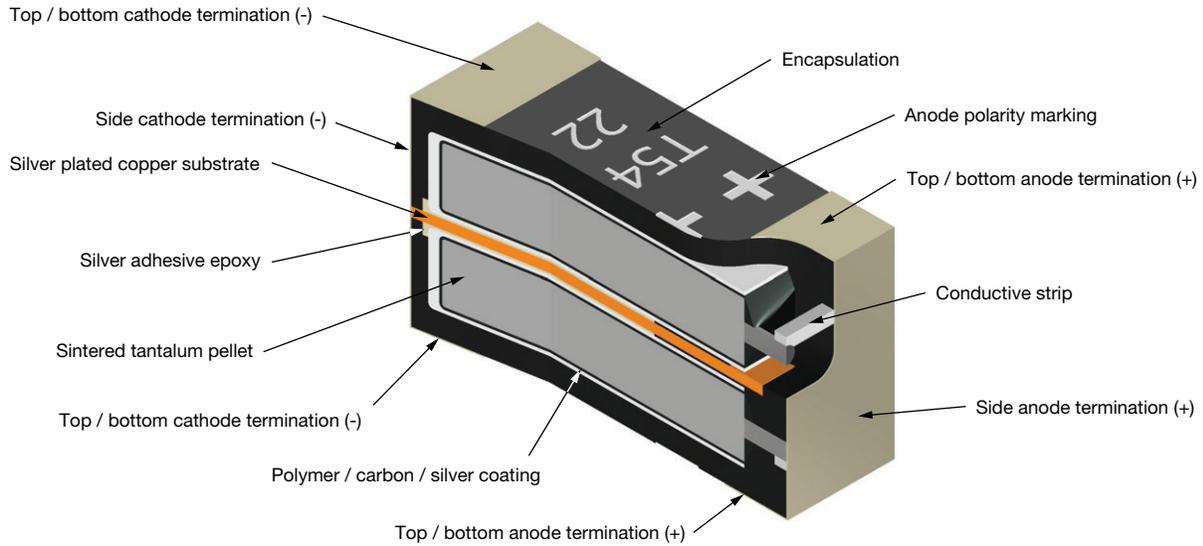
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T58



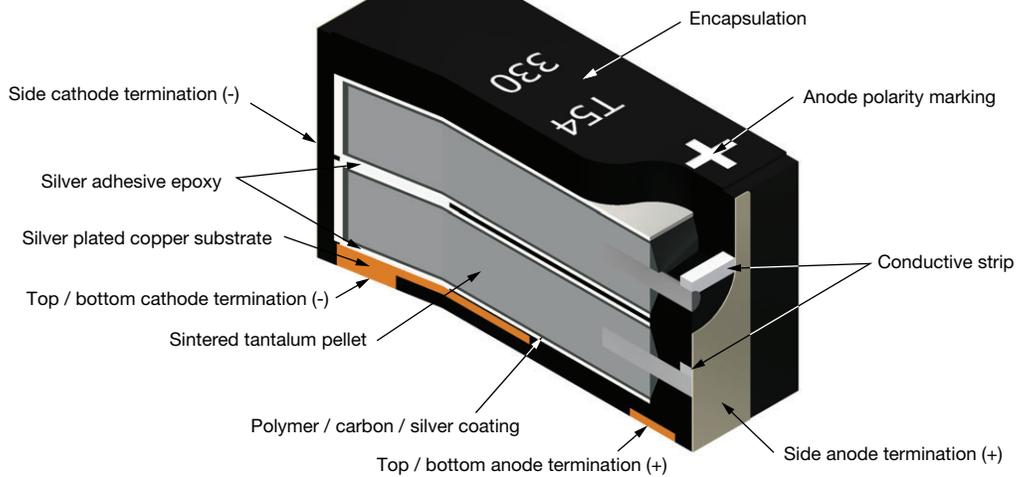
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T52



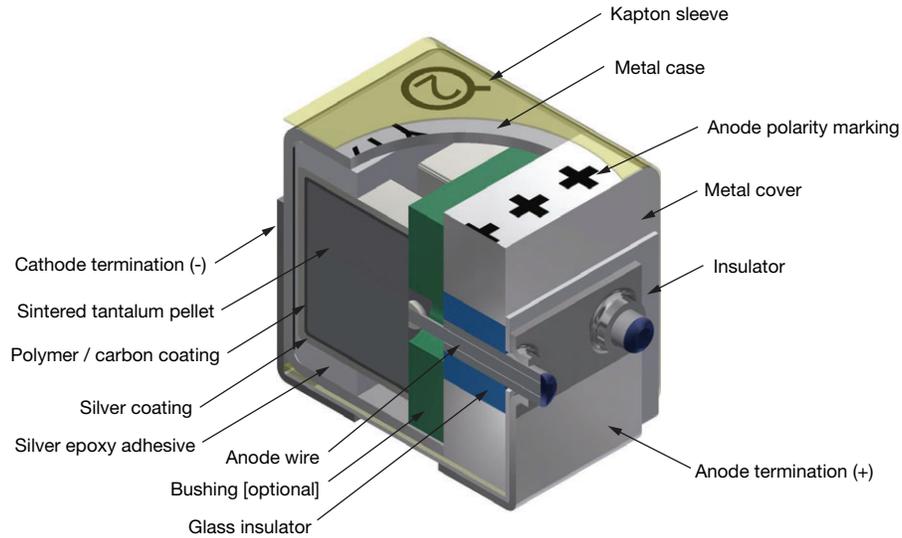
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T54 / T59 / 20021



T54 EL case



HERMETICALLY SEALED TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T27



POLYMER CAPACITORS - METAL CASE, HERMETICALLY SEALED

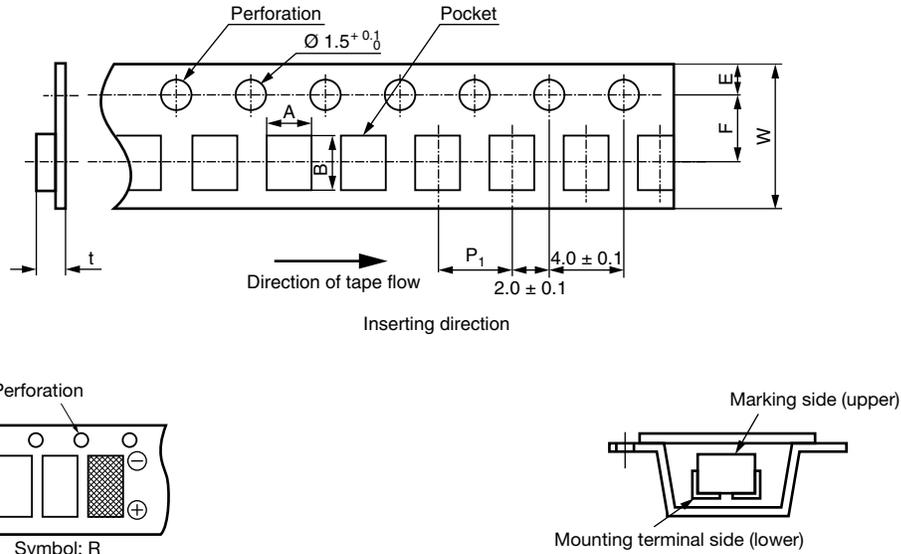
SERIES	T27
PRODUCT IMAGE	
TYPE	VPolyTan™ hermetically sealed polymer surface-mount chip capacitors, low ESR
FEATURES	Hermetically sealed in metal case, low ESR / low DCL, hi-rel. processing
TEMPERATURE RANGE	-55 °C to +125 °C
CAPACITANCE RANGE	15 µF to 470 µF
VOLTAGE RANGE	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %
LEAKAGE CURRENT	0.05 CV
DISSIPATION FACTOR	12 %
ESR	25 mΩ to 100 mΩ
CASE SIZES	D
TERMINATION FINISH	100 % tin; tin / lead

POLYMER CAPACITORS - MOLDED CASE		
SERIES	T50, T51, T55, T56	04051
PRODUCT IMAGE		
TYPE	vPolyTan™, molded case, high performance polymer	vPolyTan™, molded case, high performance polymer
FEATURES	High performance	High performance
TEMPERATURE RANGE	-55 °C to +105 °C / +125 °C (above 105 °C, additional voltage derating is required)	-55 °C to +125 °C (above +105 °C, voltage derating is required)
CAPACITANCE RANGE	1.0 µF to 1500 µF	4.7 µF to 680 µF
VOLTAGE RANGE	2.5 V to 63 V	2.5 V to 63 V
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT	0.1 CV	0.1 CV
DISSIPATION FACTOR	8 % to 10 %	8 % to 10 %
ESR	6 mΩ to 500 mΩ	25 mΩ to 125 mΩ
CASE SIZES	J, P, A, T, B, Z, V, D, C, X	B, D
TERMINATION FINISH	Cases J, P, C: 100 % tin Case A, T, B, Z, V, D: Ni / Pd / Au	All cases: tin / lead (SnPb)

POLYMER CAPACITORS - LEADFRAMELESS MOLDED CASE					
SERIES	T52	T58	T59	T54	20021
PRODUCT IMAGE					
TYPE	vPolyTan™ polymer surface mount chip capacitors, low profile, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, compact, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, hi-rel commercial off-the-shelf (COTS)	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, DLA approved
FEATURES	Low profile	Small case size	Multianode	Hi-rel COTS, multianode	Multianode
TEMPERATURE RANGE	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +125 °C (above 105 °C, additional voltage derating is required)	-55 °C to +125 °C (above 105 °C, additional voltage derating is required)	-55 °C to +125 °C (above 105 °C, additional voltage derating is required)
CAPACITANCE RANGE	47 µF to 470 µF	1 µF to 100 µF	15 µF to 470 µF	15 µF to 470 µF (discrete capacitors) 30 µF to 2800 µF (stacked capacitors)	15 µF to 470 µF (discrete capacitors) 30 µF to 2800 µF (stacked capacitors)
VOLTAGE RANGE	10 V to 35 V	6.3 V to 35 V	16 V to 75 V	16 V to 75 V	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %	± 20 %	± 10 %, ± 20 %	± 20 %	± 20 %
LEAKAGE CURRENT	0.1 CV				
DISSIPATION FACTOR	10 %	8 % to 14 %	10 % to 12 %	10 % to 12 %	10 % to 12 %
ESR	40 mΩ to 200 mΩ	90 mΩ to 500 mΩ	20 mΩ to 150 mΩ	5 mΩ to 150 mΩ	5 mΩ to 150 mΩ
CASE SIZES	E5, M1, M9, B2	MM, W0, W9, A0, BB	EE, EL	EE, EL, E2, E3, E4, E6, 3E, 6E	EE, E2, E3, E4, E6, 3E, 6E
TERMINATION	100 % tin		100 % tin; tin / lead		Tin / lead

MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES

PLASTIC TAPE SIZE DIMENSIONS in millimeters

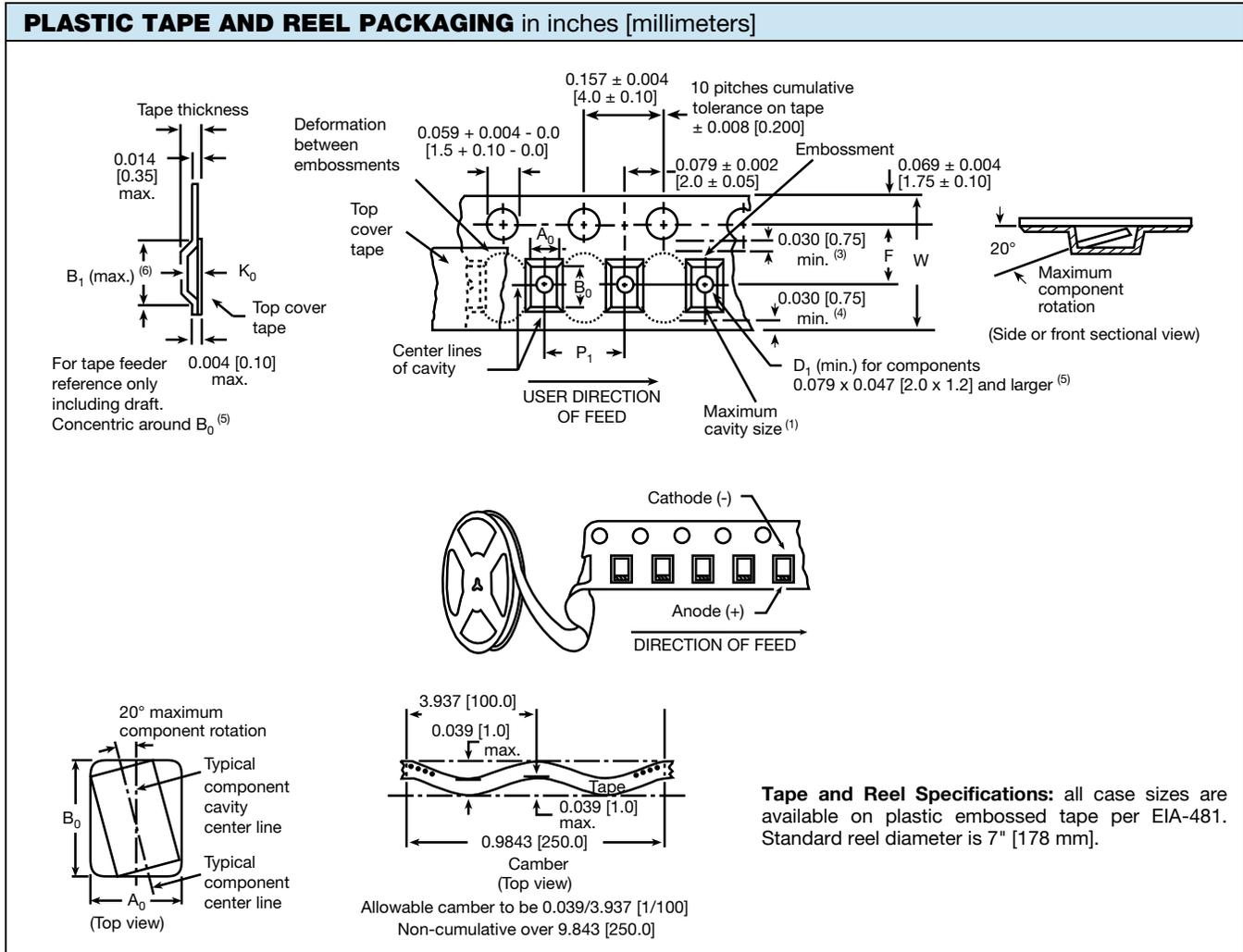


CASE CODE	A ± 0.1	B ± 0.1	W + 0.3 / - 0.1	F ± 0.05	E ± 0.1	P ₁ ± 0.1	t _{max.}
J	1.0	1.8	8.0	3.5	1.75	4.0	1.3
P	1.4	2.2	8.0	3.5	1.75	4.0	1.6
A	1.9	3.5	8.0	3.5	1.75	4.0	2.5
T	3.1	3.8	8.0	3.5	1.75	4.0	1.7
B	3.1	3.8	8.0	3.5	1.75	4.0	2.5
C	3.7	6.3	12.0	5.5	1.75	8.0	3.1
Z	4.8	7.7	12.0	5.5	1.75	8.0	2.6
V	4.8	7.7	12.0	5.5	1.75	8.0	2.6
D	4.8	7.7	12.0	5.5	1.75	8.0	3.4
X	4.8	7.7	12.0	5.5	1.75	8.0	5.1

Note

- A reel diameter of 330 mm is also applicable

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES



CARRIER TAPE DIMENSIONS in inches [millimeters]								
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	P ₂	W
E5	12 mm	0.329 [8.35]	0.059 [1.5]	0.217 ± 0.002 [5.50 ± 0.05]	0.071 [1.8]	0.315 ± 0.004 [8.0 ± 0.10]	0.079 ± 0.002 [2.00 ± 0.05]	0.476 ± 0.008 [12.1 ± 0.20]
MM ⁽²⁾	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
M1, M9	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.094 [2.39]	0.315 ± 0.04 [8.0 ± 1.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
W9	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
W0	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
A0	8 mm	-	0.02 [0.5]	0.138 [3.5]	0.049 [1.25]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
BB	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.087 [2.22]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
EE, EL	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.175 [4.44]	0.315 ± 0.04 [8.0 ± 1.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
B2	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.057 [1.45]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
D ⁽³⁾	16 mm	0.321 [8.16]	0.059 [1.5]	0.295 ± 0.004 [7.50 ± 0.1]	0.308 [7.83]	0.472 ± 0.004 [12.00 ± 0.1]	0.079 ± 0.004 [2.00 ± 0.1]	0.630 ± 0.012 [16.00 ± 0.3]
E4	24 mm	0.531 [13.5]	0.059 [1.5]	0.453 ± 0.004 [11.5 ± 0.1]	0.375 [9.53]	0.630 ± 0.004 [16.0 ± 0.1]	0.079 ± 0.004 [2.0 ± 0.1]	0.945 ± 0.012 [24.0 ± 0.3]
E6	24 mm	0.630 [16.0]	0.059 [1.5]	0.453 ± 0.004 [11.5 ± 0.1]	0.542 [13.76]	0.630 ± 0.004 [16.0 ± 0.1]	0.079 ± 0.004 [2.0 ± 0.1]	0.945 ± 0.012 [24.0 ± 0.3]
6E	24 mm	0.531 [13.5]	0.059 [1.5]	0.453 ± 0.004 [11.5 ± 0.1]	0.375 [9.53]	0.787 ± 0.004 [20.0 ± 0.1]	0.079 ± 0.004 [2.0 ± 0.1]	0.945 ± 0.012 [24.0 ± 0.3]

Notes

- (1) For reference only
- (2) Standard packaging of MM case is with paper tape. Plastic tape is available per request
- (3) Tape thickness 0.018 [0.45] max.

PAPER TAPE AND REEL PACKAGING DIMENSIONS in inches [millimeters]											
CASE SIZE	TAPE SIZE	A ₀	B ₀	D ₀	P ₀	P ₁	P ₂	E	F	W	T
MM	8 mm	0.041 ± 0.002 [1.05 ± 0.05]	0.071 ± 0.002 [1.8 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.037 ± 0.002 [0.95 ± 0.05]
M0	8 mm	0.049 ± 0.002 [1.25 ± 0.05]	0.081 ± 0.002 [2.05 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.041 ± 0.002 [1.05 ± 0.05]

Note

- (1) A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°

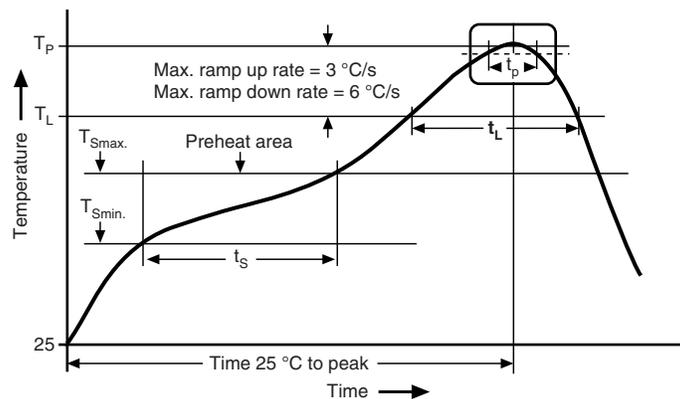
PACKING AND STORAGE

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 or 4 as specified in IPC/JEDEC® J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. MSL for each particular family is defined in the datasheet - either in “Features” section or “Standard Ratings” table. Level 3 specifies a floor life (out of bag) of 168 hours and level 4 specifies a floor life of 72 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard “dry box” conditions).

For detailed recommendations please refer to J-STD-033.

RECOMMENDED REFLOW PROFILES

Vishay recommends no more than 3 cycles of reflow in accordance with J-STD-020.



PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
PREHEAT AND SOAK		
Temperature min. ($T_{Smin.}$)	100 °C	150 °C
Temperature max. ($T_{Smax.}$)	150 °C	200 °C
Time (t_s) from ($T_{Smin.}$ to $T_{Smax.}$)	60 s to 120 s	60 s to 120 s
RAMP UP		
Ramp-up rate (T_L to T_p)	3 °C/s maximum	
Liquidus temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	
Peak package body temperature (T_p) max.	Depends on type and case - see table below	
Time (t_p) within 5 °C of the peak max. temperature	20 s	5 s ⁽¹⁾
RAMP DOWN		
Ramp-down rate (T_p to T_L)	6 °C/s maximum	
Time from 25 °C to peak temperature	6 min maximum	8 min maximum

Note

⁽¹⁾ For T27, lead (Pb)-free capacitors $t_p = 30$ s

PEAK PACKAGE BODY TEMPERATURE (T _p) MAXIMUM			
TYPE	CASE CODE	PEAK PACKAGE BODY TEMPERATURE (T _p) MAX.	
		SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
T27	D	220 °C	245 °C
T55	J, P, A, T, B, C, Z, V	n/a	260 °C
T52	E5, M1, M9, B2		260 °C
T58	MM, W9, W0, A0, BB		260 °C
T51	V		260 °C
T56	B, V		260 °C
T50, T51, T55, T56	D, X		250 °C
T59	EE, EL		220 °C
T54	EL, 3E, 6E, EE, E2, E3, E4, E6	220 °C	250 °C
20021	3E, 6E, EE, E2, E3, E4, E6	220 °C	n/a
04051	D	220 °C	n/a
04051	B	235 °C	n/a
M327001	D	220 °C	n/a
M327001	B, C	235 °C	n/a

Notes

- T50, T51, T52, T55, T56 (B, V cases), and T58 capacitors are process sensitive.
PSL classification to JEDEC J-STD-075: R4G
- T54, T59, and T50, T51, T55, T56 (D, X case) capacitors with 100 % tin termination are process sensitive.
PSL classification to JEDEC J-STD-075: R6G

MOLDED CAPACITORS, T50 / T51 / T55 / T56 / 04051 TYPES

PAD DIMENSIONS in millimeters						
CASE / DIMENSIONS	CAPACITOR SIZE		PAD DIMENSIONS			
	L	W	G (max.)	Z (min.)	X (min.)	Y (Ref.)
J	1.6	0.8	0.7	2.5	1.0	0.9
P	2.0	1.25	0.5	2.6	1.2	1.05
A	3.2	1.6	1.1	3.8	1.5	1.35
T/B	3.5	2.8	1.4	4.1	2.7	1.35
C	5.8	3.2	2.9	6.9	2.7	2.0
Z/V/D/X	7.3	4.3	4.1	8.2	2.9	2.05

LEADFRAMELESS MOLDED CAPACITORS T52 / T58

PAD DIMENSIONS in inches [millimeters]					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T52	E5	0.094 [2.40]	0.077 [1.95]	0.180 [4.57]	0.333 [8.46]
	M1, M9	0.178 [4.52]	0.098 [2.48]	0.138 [3.50]	0.333 [8.46]
	B2	0.081 [2.06]	0.057 [1.44]	0.070 [1.77]	0.183 [4.64]
T58	MM	0.024 [0.61]	0.027 [0.70]	0.025 [0.64]	0.080 [2.03]
	W0, W9	0.035 [0.89]	0.029 [0.74]	0.041 [1.05]	0.099 [2.52]
	A0	0.047 [1.19]	0.042 [1.06]	0.065 [1.65]	0.148 [3.76]
	BB	0.094 [2.39]	0.044 [1.11]	0.072 [1.82]	0.159 [4.03]

LEADFRAMELESS MOLDED CAPACITORS T59 / T54 / 20021

PAD DIMENSIONS in inches [millimeters]					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T59 / T54	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]
	EL	0.098 [2.50]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]
T54	E2 / E3	0.128 [3.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	E4 / E6	0.301 [7.64]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	3E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	6E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
20021	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]

HERMETICALLY SEALED CAPACITOR T27 TYPE

PAD DIMENSIONS in inches [millimeters]				
CASE CODE	A (MIN.)	B (NOM.)	C (NOM.)	D (NOM.)
D	0.295 [7.50]	0.138 [3.50]	0.100 [2.50]	0.374 [9.50]

GUIDE TO APPLICATION

- AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

- AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

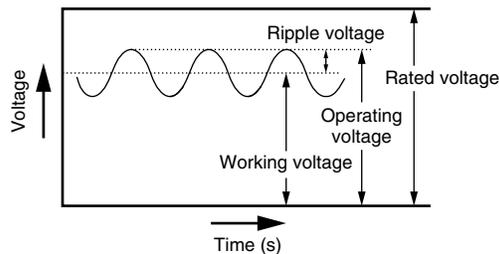
where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

- The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



- Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR	
≤ 45 °C	1.0
55 °C	0.8
85 °C	0.6
105 °C	0.4
125 °C	0.25

- Reverse Voltage:** the capacitors are not intended for use with reverse voltage applied. However, they are capable of withstanding momentary reverse voltage peaks, which must not exceed the following values:

At 25 °C: 10 % of the rated voltage or 1 V, whichever is smaller.

At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.

At 105 °C: 3 % of the rated voltage or 0.3 V, whichever is smaller.

- Mounting Precautions:**

- Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see www.vishay.com/doc?40214.

- Limit Pressure on Capacitor Installation with Mounter:** pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

- Flux Selection**

- Select a flux that contains a minimum of chlorine and amine.

- After flux use, the chlorine and amine in the flux remain must be removed.

- Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout



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